

# 74LVT244A; 74LVTH244A

3.3 V octal buffer/line driver; 3-state

Rev. 04 — 3 September 2008

Product data sheet

## 1. General description

The 74LVT244A; 74LVTH244A is a high-performance BiCMOS product designed for  $V_{CC}$  operation at 3.3 V.

This device is an octal buffer that is ideal for driving bus lines. The device features two output enables ( $\overline{1OE}$ ,  $\overline{2OE}$ ), each controlling four of the 3-state outputs.

## 2. Features

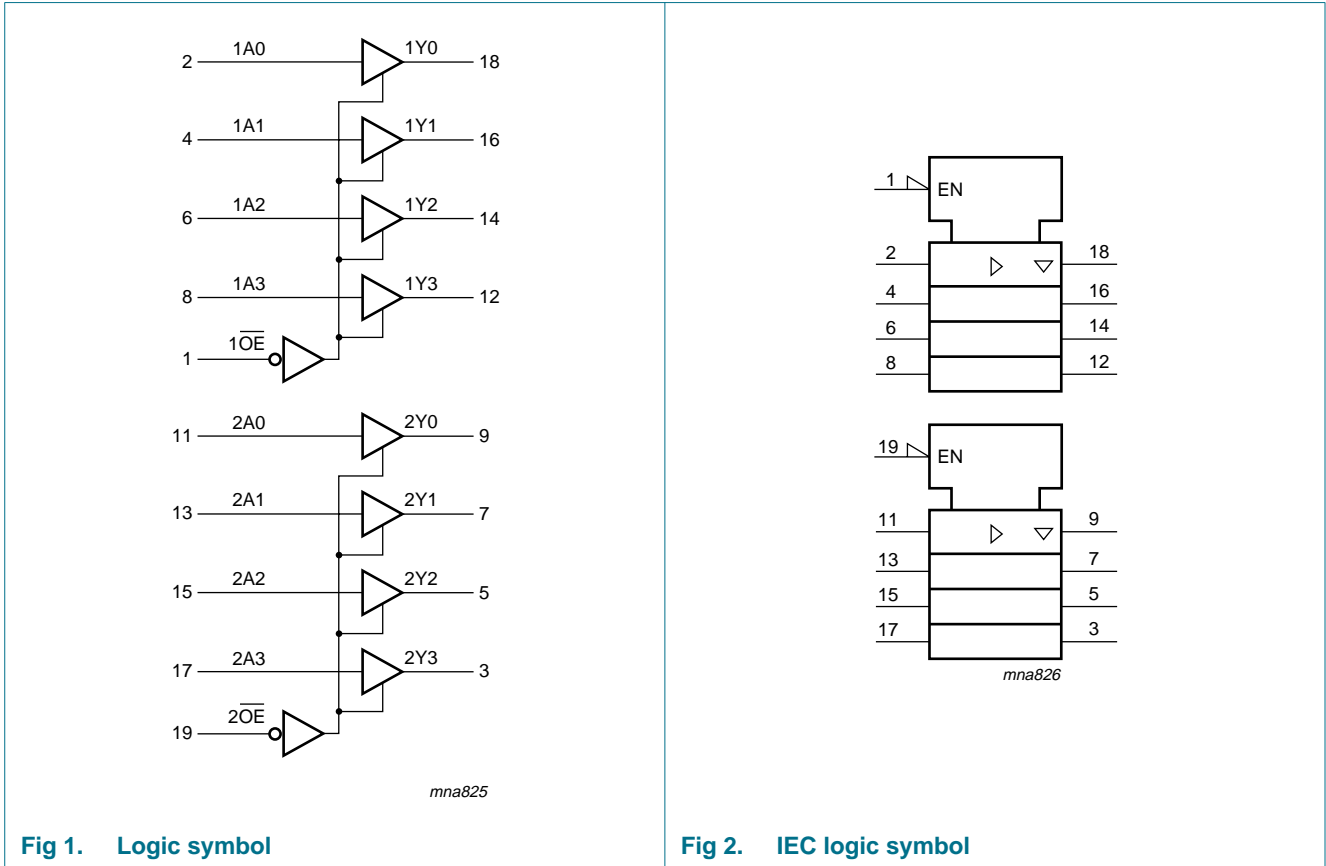
- Octal bus interface
- 3-state buffers
- Output capability: +64 mA and -32 mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5 V supply
- Bus hold data inputs eliminate need for external pull-up resistors to hold unused inputs
- Live insertion and extraction permitted
- Power-up 3-state
- No bus current loading when output is tied to 5 V bus
- Latch-up protection
  - ◆ JESD78 Class II exceeds 500 mA
- ESD protection:
  - ◆ HBM JESD22-A114E exceeds 2000 V
  - ◆ MM JESD22-A115-A exceeds 200 V

## 3. Ordering information

Table 1. Ordering information

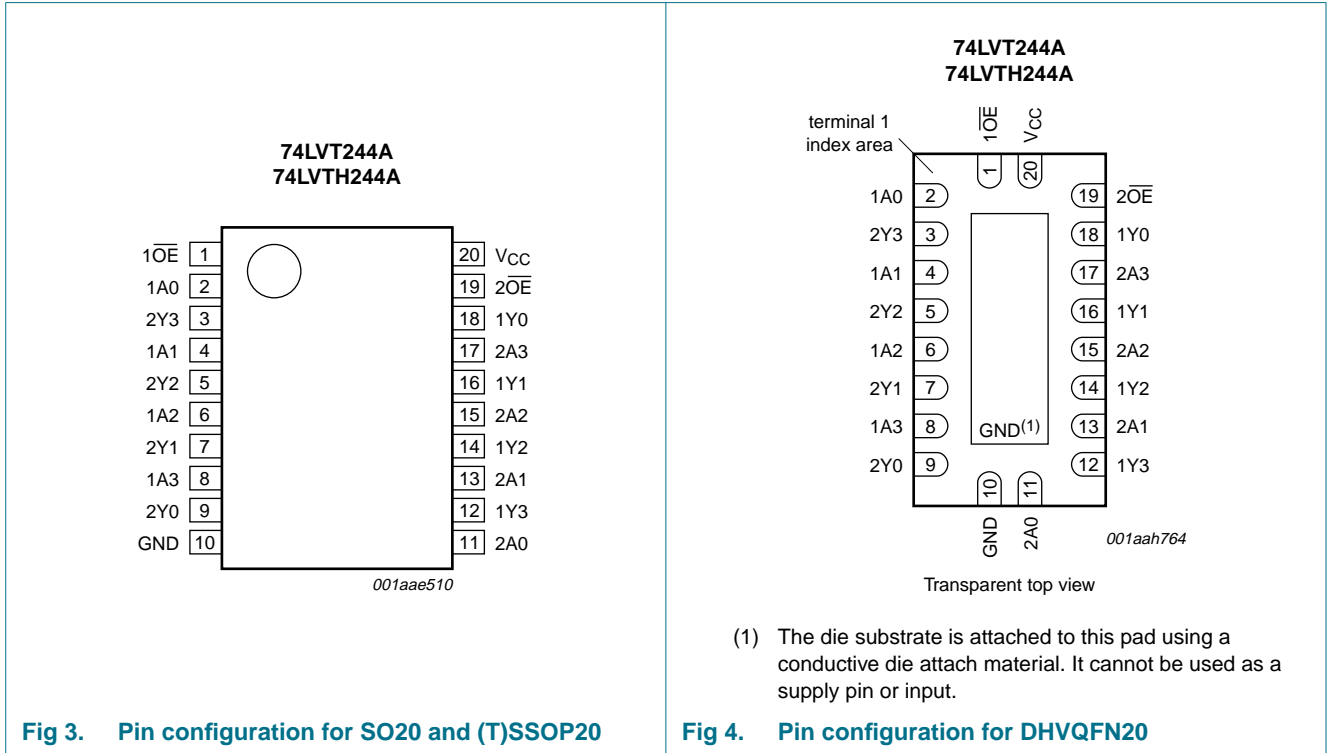
Type number	Package			
	Temperature range	Name	Description	Version
74LVT244AD 74LVTH244AD	-40 °C to +85 °C	SO20	plastic small outline package; 20 leads; body width 7.5 mm	SOT163-1
74LVT244ADB 74LVTH244ADB	-40 °C to +85 °C	SSOP20	plastic shrink small outline package; 20 leads; body width 5.3 mm	SOT339-1
74LVT244APW 74LVTH244APW	-40 °C to +85 °C	TSSOP20	plastic thin shrink small outline package; 20 leads; body width 4.4 mm	SOT360-1
74LVT244ABQ 74LVTH244ABQ	-40 °C to +85 °C	DHVQFN20	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 20 terminals; body 2.5 × 4.5 × 0.85 mm	SOT764-1

## 4. Functional diagram



## 5. Pinning information

### 5.1 Pinning



### 5.2 Pin description

**Table 2. Pin description**

Symbol	Pin	Description
$1\overline{OE}$ , $2\overline{OE}$	1, 19	output enable input (active low)
1A0, 1A1, 1A2, 1A3	2, 4, 6, 8	data input
2Y0, 2Y1, 2Y2, 2Y3	9, 7, 5, 3	data output
GND	10	ground (0 V)
2A0, 2A1, 2A2, 2A3	11, 13, 15, 17	data input
1Y0, 1Y1, 1Y2, 1Y3	18, 16, 14, 12	data output
V <sub>CC</sub>	20	supply voltage

## 6. Functional description

### 6.1 Function table

Table 3. Function table [1]

Control	Input	Output
nOE	nAn	nYn
L	L	L
	H	H
H	X	Z

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

## 7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+4.6	V
V <sub>I</sub>	input voltage		[1] -0.5	+7.0	V
V <sub>O</sub>	output voltage	output in OFF-state or HIGH-state	[1] -0.5	+7.0	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V	-	-50	mA
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V	-	-50	mA
I <sub>O</sub>	output current	output in LOW-state	-	128	mA
		output in HIGH-state	-	-64	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
T <sub>j</sub>	junction temperature		[2] -	150	°C
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = -40 to +85 °C	[3]	500	mW

- [1] The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.
- [2] The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability.
- [3] For SO20 packages: above 70 °C derate linearly with 8 mW/K.  
 For SSOP20 and TSSOP20 packages: above 60 °C derate linearly with 5.5 mW/K.  
 For DHVQFN20 packages: above 60 °C derate linearly with 4.5 mW/K.

## 8. Recommended operating conditions

Table 5. Operating conditions

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V <sub>CC</sub>	supply voltage		2.7	-	3.6	V
V <sub>I</sub>	input voltage		0	-	5.5	V
I <sub>OH</sub>	HIGH-level output current		-	-	-32	mA

**Table 5. Operating conditions ...continued**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I <sub>OL</sub>	LOW-level output current	none	-	-	32	mA
		current duty cycle ≤ 50 %; f <sub>i</sub> ≥ 1 kHz	-	-	64	mA
T <sub>amb</sub>	ambient temperature	in free-air	-40	-	+85	°C
Δt/ΔV	input transition rise and fall rate	outputs enabled	-	-	10	ns/V

## 9. Static characteristics

**Table 6. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>T<sub>amb</sub> = -40 °C to +85 °C [1]</b>						
V <sub>IK</sub>	input clamping voltage	V <sub>CC</sub> = 2.7 V; I <sub>IK</sub> = -18 mA	-1.2	-0.9	-	V
V <sub>IH</sub>	HIGH-level input voltage		2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage		-	-	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>CC</sub> = 2.7 V to 3.6 V; I <sub>OH</sub> = -100 μA	V <sub>CC</sub> - 0.2	V <sub>CC</sub> - 0.1	-	V
		V <sub>CC</sub> = 2.7 V to 3.6 V; I <sub>OH</sub> = -8 mA	2.4	2.5	-	V
		V <sub>CC</sub> = 3.0 V; I <sub>OH</sub> = -32 mA	2.0	2.2	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>CC</sub> = 2.7 V; I <sub>OL</sub> = 100 μA	-	0.1	0.2	V
		V <sub>CC</sub> = 2.7 V; I <sub>OL</sub> = 24 mA	-	0.3	0.5	V
		V <sub>CC</sub> = 3.0 V; I <sub>OL</sub> = 16 mA	-	0.25	0.4	V
		V <sub>CC</sub> = 3.0 V; I <sub>OL</sub> = 32 mA	-	0.3	0.5	V
		V <sub>CC</sub> = 3.0 V; I <sub>OL</sub> = 64 mA	-	0.4	0.55	V
I <sub>I</sub>	input leakage current	all input pins				
		V <sub>CC</sub> = 0 V or 3.6 V; V <sub>I</sub> = 5.5 V	-	0.1	10	μA
		control pins				
		V <sub>CC</sub> = 3.6 V; V <sub>I</sub> = V <sub>CC</sub> or GND	-	±0.1	±1	μA
		data pins [2]				
		V <sub>CC</sub> = 3.6 V; V <sub>I</sub> = V <sub>CC</sub>	-	0.1	1	μA
		V <sub>CC</sub> = 3.6 V; V <sub>I</sub> = 0 V	-5	-1	-	μA
I <sub>OFF</sub>	power-off leakage current	V <sub>CC</sub> = 0 V; V <sub>I</sub> or V <sub>O</sub> = 0 V to 4.5 V	-	1	±100	μA
I <sub>BHL</sub>	bus hold LOW current	V <sub>CC</sub> = 3 V; V <sub>I</sub> = 0.8 V [3]	75	150	-	μA
I <sub>BHH</sub>	bus hold HIGH current	V <sub>CC</sub> = 3 V; V <sub>I</sub> = 2.0 V	-	-150	-75	μA
I <sub>BHLO</sub>	bus hold LOW overdrive current	nAn input; V <sub>CC</sub> = 0 V to 3.6 V; V <sub>I</sub> = 3.6 V	500	-	-	μA
I <sub>BHHO</sub>	bus hold HIGH overdrive current	nAn input; V <sub>CC</sub> = 0 V to 3.6 V; V <sub>I</sub> = 3.6 V	-	-	-500	μA
I <sub>LO</sub>	output leakage current	nYn output in HIGH-state when V <sub>O</sub> > V <sub>CC</sub> ; V <sub>O</sub> = 5.5 V; V <sub>CC</sub> = 3.0 V	-	60	125	μA
I <sub>O(pu/pd)</sub>	power-up/power-down output current	V <sub>CC</sub> ≤ 1.2 V; V <sub>O</sub> = 0.5 V to V <sub>CC</sub> ; V <sub>I</sub> = GND or V <sub>CC</sub> ; nOE = don't care [4]	-	±1	±100	μA

**Table 6. Static characteristics ...continued**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
I <sub>OZ</sub>	OFF-state output current	V <sub>CC</sub> = 3.6 V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>					
		V <sub>O</sub> = 3.0 V	-	1	5	μA	
		V <sub>O</sub> = 0.5 V	-5	-1	-	μA	
I <sub>CC</sub>	supply current	V <sub>CC</sub> = 3.6 V; V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A					
		output HIGH	-	0.13	0.19	mA	
		output LOW	-	3	12	mA	
		outputs disabled	[5]	-	0.13	0.19	mA
ΔI <sub>CC</sub>	additional supply current	per input pin; V <sub>CC</sub> = 3.0 V to 3.6 V; one input at V <sub>CC</sub> - 0.6 V and other inputs at V <sub>CC</sub> or GND	[6]	-	0.1	0.2	mA
C <sub>I</sub>	input capacitance	V <sub>I</sub> = 0 V or 3.0 V	-	4	-	pF	
C <sub>O</sub>	output capacitance	outputs disabled; V <sub>O</sub> = 0 V or 3.0 V	-	8	-	pF	

[1] All typical values are at T<sub>amb</sub> = 25 °C.

[2] Unused pins at V<sub>CC</sub> or GND.

[3] This is the bus hold overdrive current required to force the input to the opposite logic state.

[4] This parameter is valid for any V<sub>CC</sub> between 0 V and 1.2 V with a transition time of up to 10 ms. From V<sub>CC</sub> = 1.2 V to V<sub>CC</sub> = 3.3 V ± 0.3 V a transition time of 100 μs is permitted. This parameter is valid for T<sub>amb</sub> = 25 °C only.

[5] I<sub>CC</sub> is measured with outputs pulled to V<sub>CC</sub> or GND.

[6] This is the increase in supply current for each input at the specified voltage level other than V<sub>CC</sub> or GND.

## 10. Dynamic characteristics

**Table 7. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 7](#).

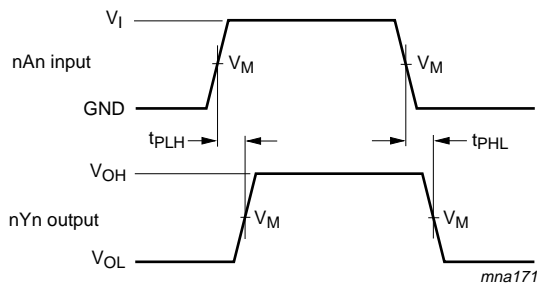
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>T<sub>amb</sub> = -40 °C to +85 °C [1]</b>						
t <sub>PLH</sub>	LOW to HIGH propagation delay	nAn to nYn; see <a href="#">Figure 5</a>				
		V <sub>CC</sub> = 2.7 V	-	-	5.0	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1	2.5	4.1	ns
t <sub>PHL</sub>	HIGH to LOW propagation delay	nAn to nYn; see <a href="#">Figure 5</a>				
		V <sub>CC</sub> = 2.7 V	-	-	5.1	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1	2.6	4.1	ns
t <sub>PZH</sub>	OFF-state to HIGH propagation delay	see <a href="#">Figure 6</a>				
		V <sub>CC</sub> = 2.7 V	-	-	6.3	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1	3.2	5.2	ns
t <sub>PZL</sub>	OFF-state to LOW propagation delay	see <a href="#">Figure 6</a>				
		V <sub>CC</sub> = 2.7 V	-	-	6.7	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.1	3.1	5.2	ns
t <sub>PHZ</sub>	HIGH to OFF-state propagation delay	see <a href="#">Figure 6</a>				
		V <sub>CC</sub> = 2.7 V	-	-	6.3	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.9	3.3	5.6	ns

**Table 7. Dynamic characteristics ...continued**  
 Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 7](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$t_{PLZ}$	LOW to OFF-state propagation delay	see <a href="#">Figure 6</a>				
		$V_{CC} = 2.7\text{ V}$	-	-	5.6	ns
		$V_{CC} = 3.0\text{ V to }3.6\text{ V}$	1.8	3.3	5.1	ns

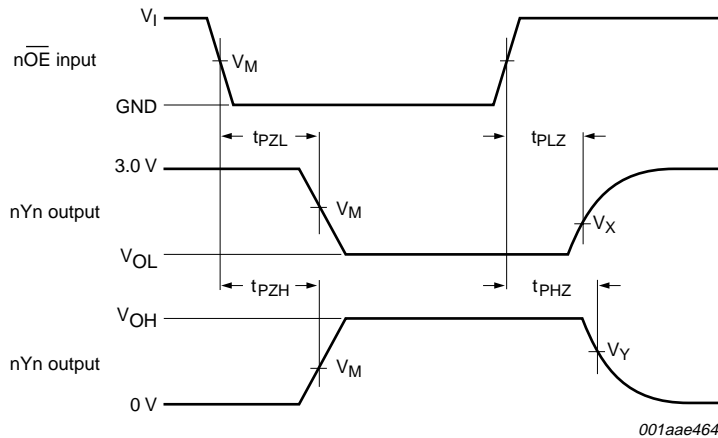
[1] All typical values are at  $V_{CC} = 3.3\text{ V}$  and  $T_{amb} = 25\text{ }^\circ\text{C}$ .

## 11. Waveforms



Measurement points are given in [Table 8](#).  
 $V_{OL}$  and  $V_{OH}$  are typical voltage output levels that occur with the output load.

**Fig 5. Propagation delay input (nAn) to output (nYn) propagation delays**

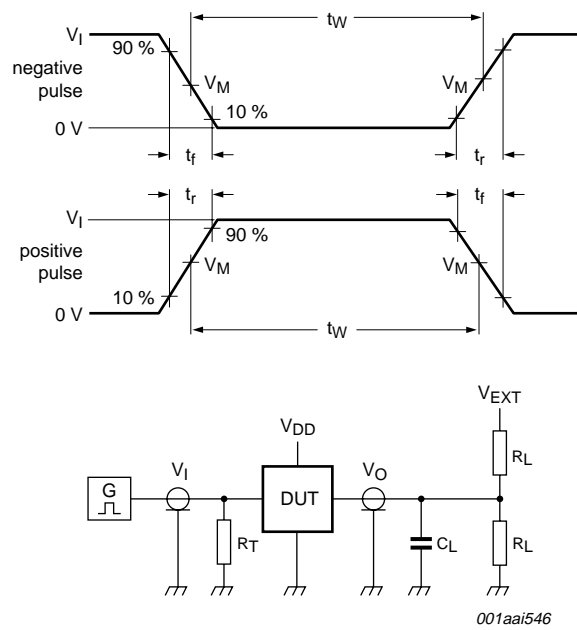


Measurement points are given in [Table 8](#).  
 $V_{OL}$  and  $V_{OH}$  are typical voltage output levels that occur with the output load.

**Fig 6. 3-state output enable and disable times**

**Table 8. Measurement points**

Input	Output		
$V_M$	$V_M$	$V_X$	$V_Y$
1.5 V	1.5 V	$V_{OL} + 0.3\text{ V}$	$V_{OH} - 0.3\text{ V}$



Test data is given in [Table 9](#).

Definitions test circuit:

$R_L$  = Load resistance.

$C_L$  = Load capacitance including jig and probe capacitance.

$R_T$  = Termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.

$V_{EXT}$  = Test voltage for switching times.

**Fig 7. Load circuitry for switching times**

**Table 9. Test data**

Input				Load		$V_{EXT}$		
$V_I$	$f_i$	$t_W$	$t_r, t_f$	$C_L$	$R_L$	$t_{PHZ}, t_{PZH}$	$t_{PLZ}, t_{PZL}$	$t_{PLH}, t_{PHL}$
2.7 V	$\leq 10$ MHz	500 ns	$\leq 2.5$ ns	50 pF	500 $\Omega$	GND	6 V	open



12. Package outline

SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1

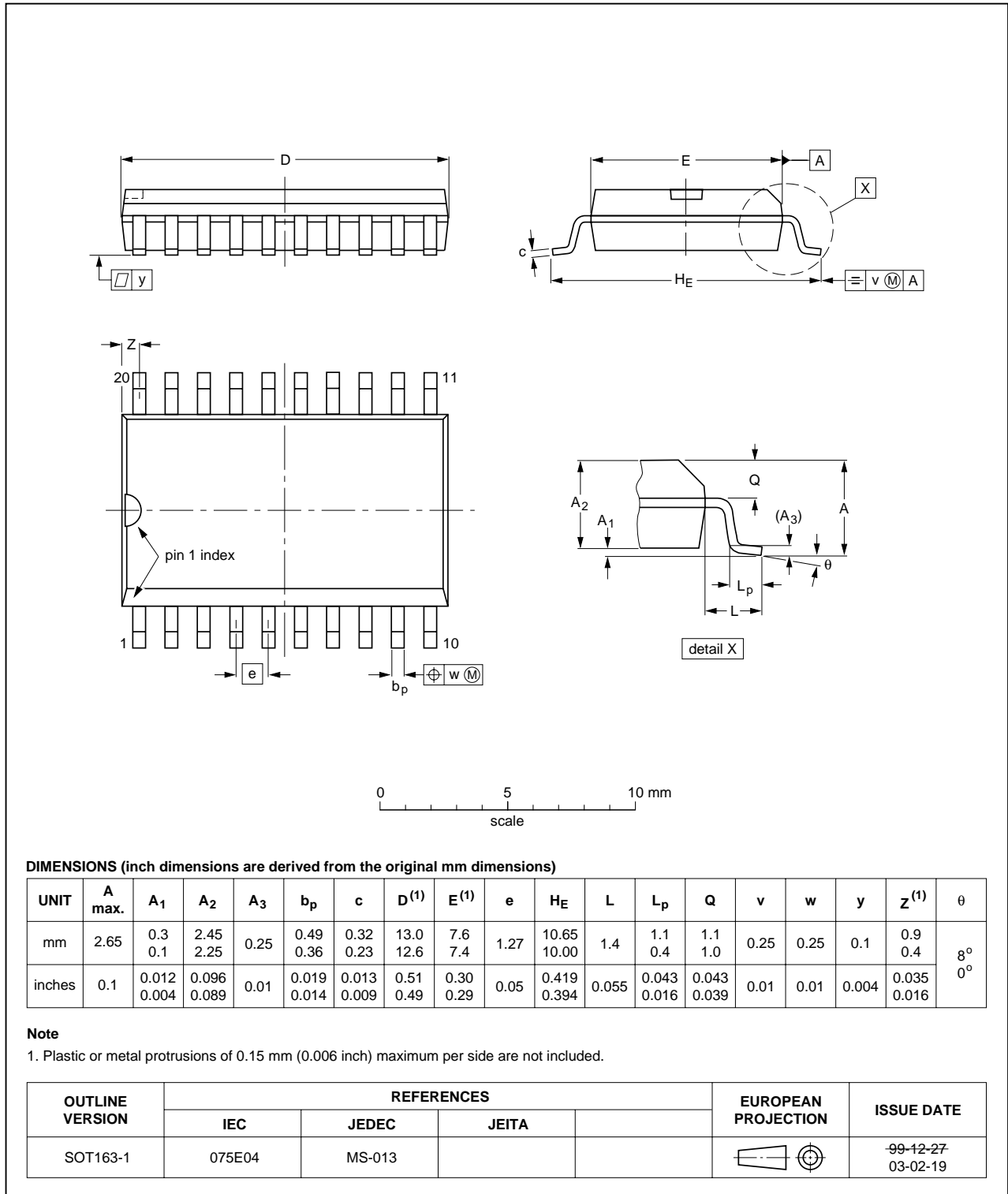


Fig 8. Package outline SOT163-1 (SO20)

SSOP20: plastic shrink small outline package; 20 leads; body width 5.3 mm

SOT339-1

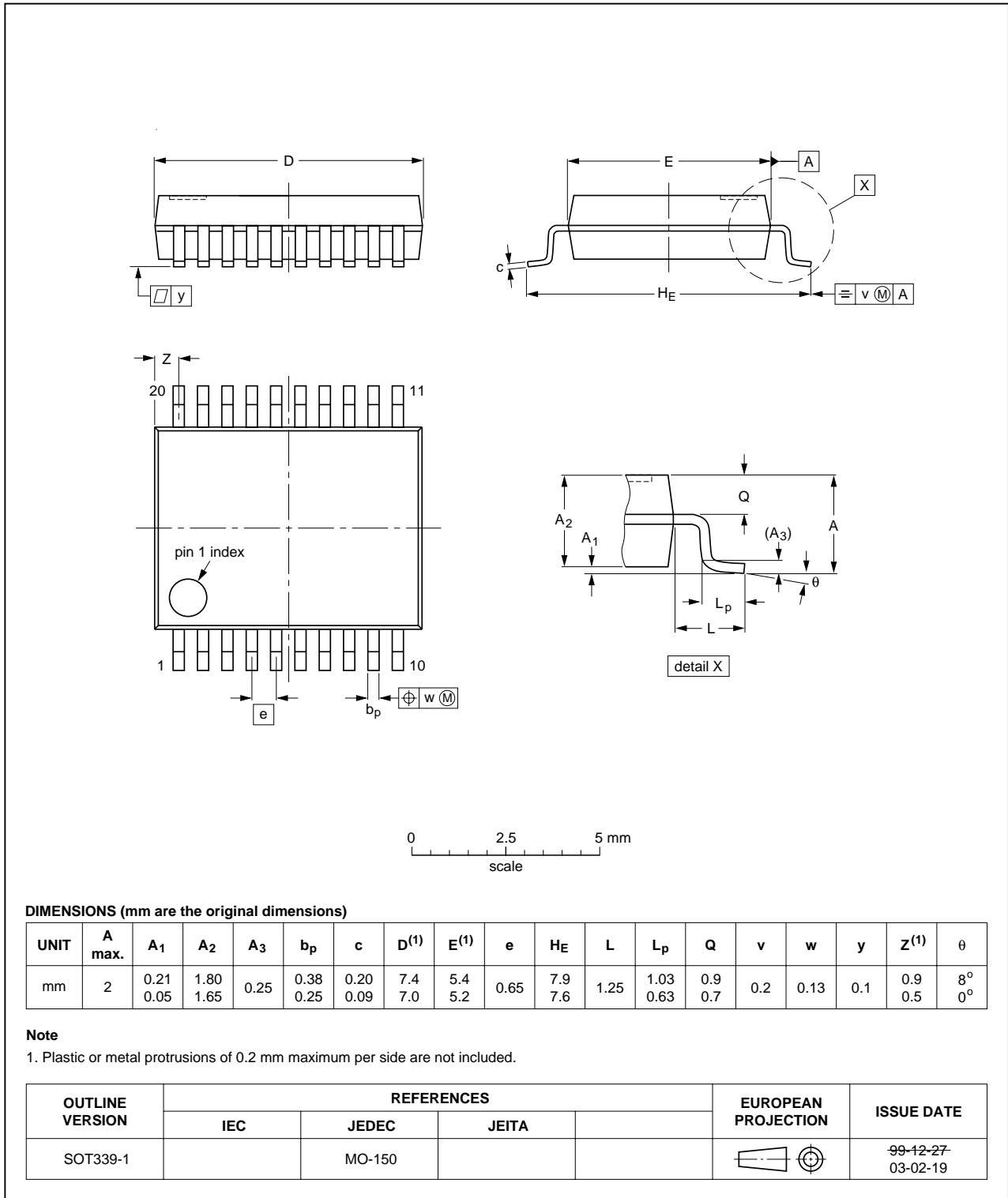


Fig 9. Package outline SOT339-1 (SSOP20)

TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1

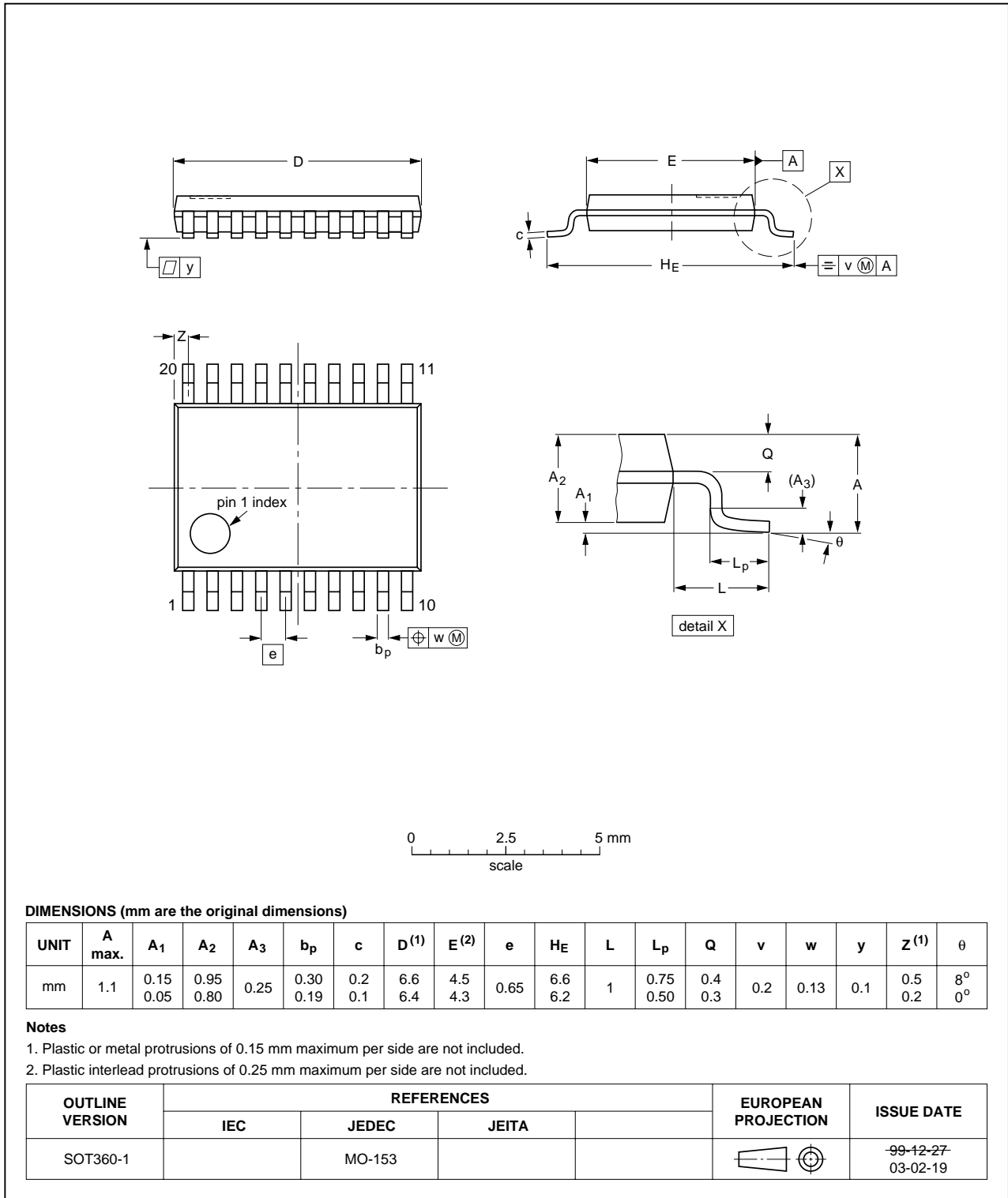


Fig 10. Package outline SOT360-1 (TSSOP20)

DHVQFN20: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 20 terminals; body 2.5 x 4.5 x 0.85 mm

SOT764-1

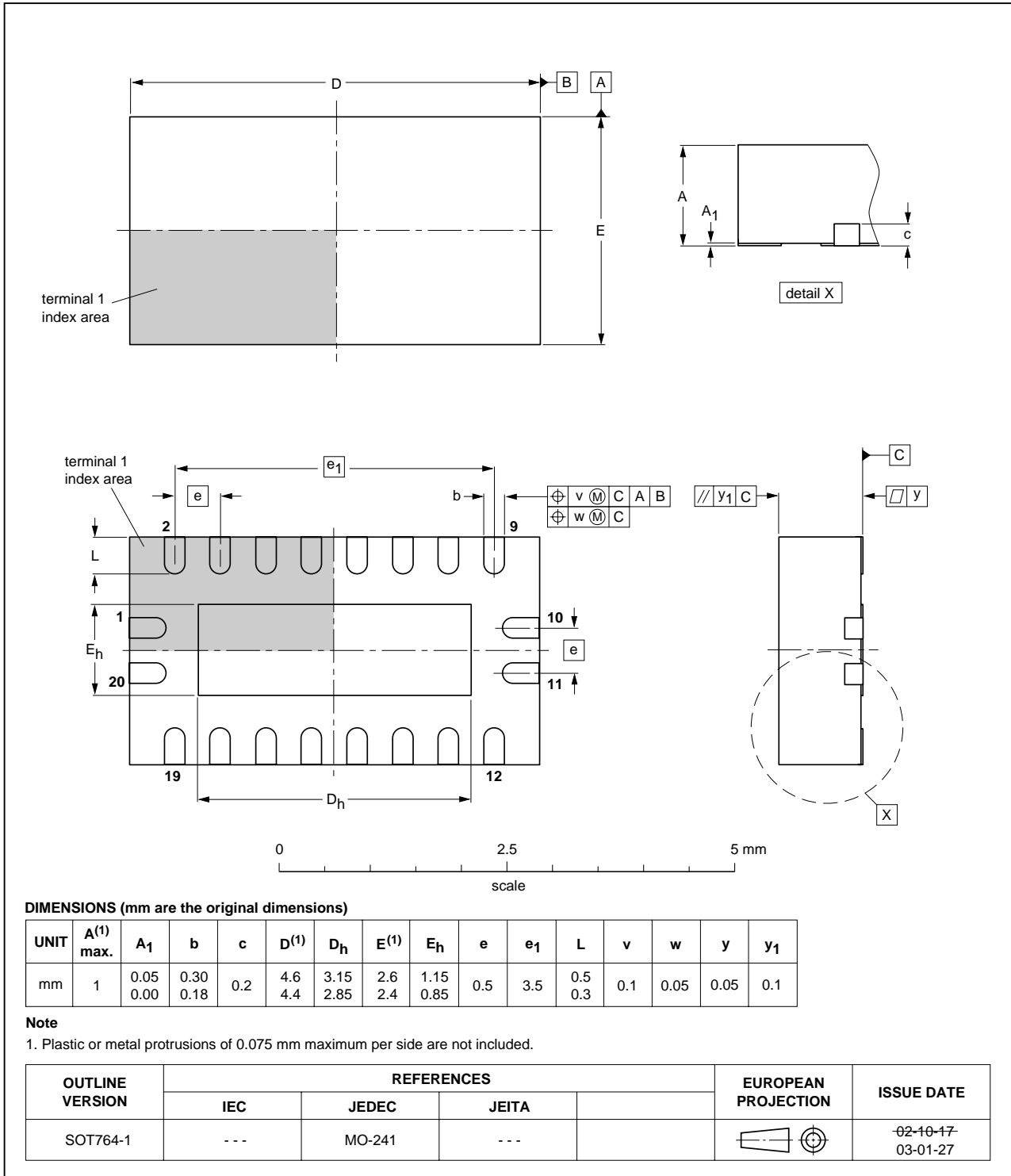


Fig 11. Package outline SOT764-1 (DHVQFN20)

## 13. Abbreviations

Table 10. Abbreviations

Acronym	Description
BiCMOS	Bipolar Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

## 14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVT_LVTH244A_4	20080903	Product data sheet	-	74LVT_LVTH244A_3
Modifications:	<ul style="list-style-type: none"> <li>The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li><a href="#">Section 3 "Ordering information"</a> and <a href="#">Section 12 "Package outline"</a> DHVQFN20 package added.</li> </ul>			
74LVT_LVTH244A_3	20060315	Product specification	-	74LVT244A_2
74LVT244A_2	19980219	Product specification	-	74LVT244A_1

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### 15.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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[2] The term 'short data sheet' is explained in section "Definitions".

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